PUUP8BH – PUUP8DH

Taiwan Semiconductor

8A, 100V - 200V Ultra Fast Surface Mount Rectifier

FEATURES

- AEC-Q101 qualified
- Planar technology
- Low power loss, high efficiency
- Ideal for automated placement
- Wettable flank
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- High frequency switching
- DC/DC
- Snubber

MECHANICAL DATA

- Case: TO-277A (SMPC4.6U)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.104g (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
١ _F	8	А	
V _{RRM}	100 - 200	V	
I _{FSM}	200	А	
T _{J MAX}	175 °C		
Package	TO-277A (SMPC4.6U)		
Configuration	Single die		
PbFree ROHS COMPLIANT HALOGEN			



TO-277A (SMPC4.6U)

Anode 1 Anode 2

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	PUUP8BH	PUUP8DH	UNIT
Marking code on the device			PU8BH	PU8DH	
Repetitive peak reverse voltage		V _{RRM}	100	200	V
Reverse voltage, total rms value		V _{R(RMS)}	70	140	V
Forward current		١ _F	8		Α
Surge peak forward current single half	t = 8.3ms		200		A
sine-wave superimposed on rated load	t = 1.0ms	I _{FSM}	410		
Junction temperature		TJ	-55 to +175		°C
Storage temperature		T _{STG}	-55 to +175		°C





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THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-lead thermal resistance ⁽¹⁾	R _{ƏJL}	2.0	°C/W	
Junction-to-ambient thermal resistance ⁽²⁾	R _{ØJA}	48.7	°C/W	
Junction-to-case thermal resistance ⁽²⁾	R _{eJC}	9.0	°C/W	

Thermal Performance Notes:

1. With ideal heat sink

2. Units mounted on PCB (16mm x 16mm Cu pad test board)

PARAMETER	CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage ⁽¹⁾	$I_F = 4A, T_J = 25^{\circ}C$		0.81	-	V
	$I_{F} = 8A, T_{J} = 25^{\circ}C$	V	0.88	1.05	V
	$I_F = 4A, T_J = 125^{\circ}C$	V _F	0.67	-	V
	$I_F = 8A, T_J = 125^{\circ}C$	-	0.75	-	V
Deverse everent @ reted \/ ⁽²⁾	$T_J = 25^{\circ}C$	-	2	μA	
Reverse current @ rated $V_R^{(2)}$	$T_J = 125^{\circ}C$	I _R	-	15	μA
Junction capacitance	1MHz, V _R = 4.0V	CJ	96	-	pF
	$I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A$		-	25	ns
Reverse recovery time	$I_F = 1.0A$, di/dt = 50A/µs, $V_R = 30V$	t _{rr}	31	-	
Reverse recovery current		I _{RM}	5.6	-	Α
Reverse recovery charge	$I_F = 8.0A$, di/dt = 200A/µs, $V_R = 100V$	Q _{rr}	89	-	nC
Reverse recovery time	1	t _{rr}	31	-	ns

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION

ORDERING CODE ⁽¹⁾	PACKAGE	PACKING
PUUP8xH	TO-277A (SMPC4.6U)	6,000/ Tape & Reel

Notes:

1. "x" defines voltage from 100V(PUUP8BH) to 200V(PUUP8DH)



f=1.0MHz Vsig=50mVp-p

100

CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

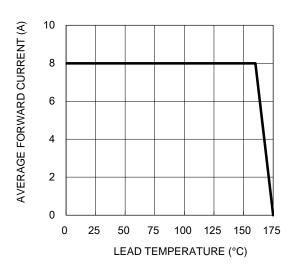
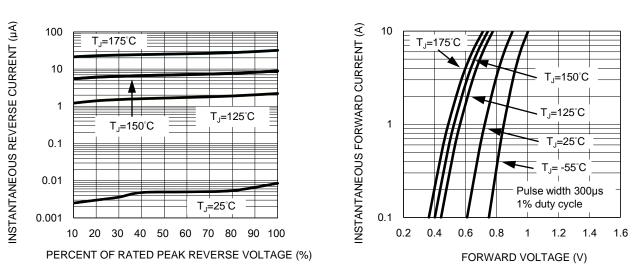


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics



1000

100

10

1

CAPACITANCE (pF)

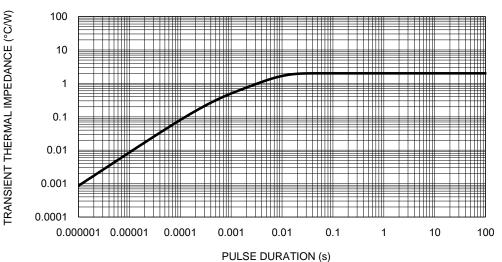


Fig.5 Typical Transient Thermal Impedance

Fig.2 Typical Junction Capacitance

10

Fig.4 Typical Forward Characteristics

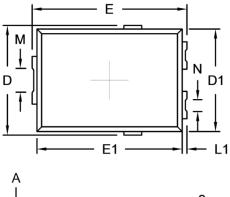
REVERSE VOLTAGE (V)

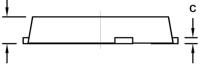
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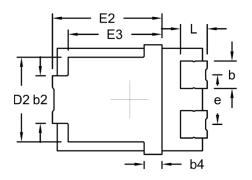


PACKAGE OUTLINE DIMENSIONS

TO-277A (SMPC4.6U)







SUGGESTED PAD LAYOUT

DIM.	Unit (mm)		Unit ((inch)
	Min.	Max.	Min.	Max.
A	1.00	1.20	0.039	0.047
b	1.05	1.35	0.041	0.053
b2	1.90	2.20	0.075	0.087
b4	0.75 (NOM.)	0.030	(NOM.)
с	0.15	0.40	0.006	0.016
D	4.45	4.75	0.175	0.187
D1	4.25	4.35	0.167	0.171
D2	3.40	3.70	0.134	0.146
E	6.35	6.65	0.250	0.262
E1	6.05	6.15	0.238	0.242
E2	4.40	4.80	0.173	0.189
E3	3.94 (NOM.)		0.155	(NOM.)
е	2.08 (NOM.)		0.082	(NOM.)
L	0.94	1.24	0.037	0.049
L1	0.05	0.35	0.002	0.014
М	0.65	1.15	0.026	0.045
N	0.25	0.75	0.010	0.030

Package body size D1 and E1 do not include mold flash Mold flash shall not exceed 0.1mm per side

В D ١ F С 1 Е

Symbol	Unit (mm)	Unit (inch)
А	4.95	0.195
В	4.95	0.195
С	1.60	0.063
D	1.42	0.056
E	6.95	0.274
F	1.04	0.041

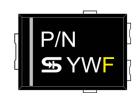
Notes:

А

1

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

MARKING DIAGRAM



= Marking Code

YW F

P/N

= Date Code

= Factory Code

Version: A2111



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